



安徽富信半导体科技有限公司

ANHUI FOSAN SEMICONDUCTOR TECHNOLOGY CO., LTD.

ES2A THRU ES2J 2.0 AMP SURFACE MOUNT SUPER FAST RECTIFIERS



FEATURES

- * Ideal for surface mount applications
- * Easy pick and place
- * Built-in strain relief
- * Low forward voltage drop

MECHANICAL DATA

- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Metallurgically bonded construction
- * Polarity: Color band denotes cathode end
- * Mounting position: Any
- * Weight: 0.093 grams

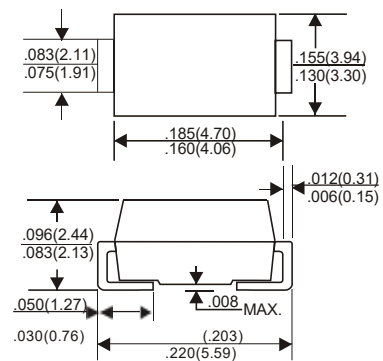
VOLTAGE RANGE

50 to 600 Volts

CURRENT

2.0 Amperes

DO-214AA(SMB)



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25 °C ambient temperature unless otherwise specified.

Single phase half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

TYPE NUMBER	ES2A	ES2B	ES2C	ES2D	ES2E	ES2G	ES2J	UNITS	
Maximum Recurrent Peak Reverse Voltage	50	100	150	200	300	400	600	V	
Maximum RMS Voltage	35	70	105	140	210	280	420	V	
Maximum DC Blocking Voltage	50	100	150	200	300	400	600	V	
Maximum Average Forward Rectified Current									
.375"(9.5mm) Lead Length at Ta=55 C								2.0	A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)								60	A
Maximum Instantaneous Forward Voltage at 2.0A	0.95			1.25		1.70		V	
Maximum DC Reverse Current Ta=25 C								5.0	μA
at Rated DC Blocking Voltage Ta=100 C								500	μA
Maximum Reverse Recovery Time (Note 1)								35	nS
Typical Junction Capacitance (Note 2)								60	pF
Operating and Storage Temperature Range T _J , T _{STG}								-65—+150	°C

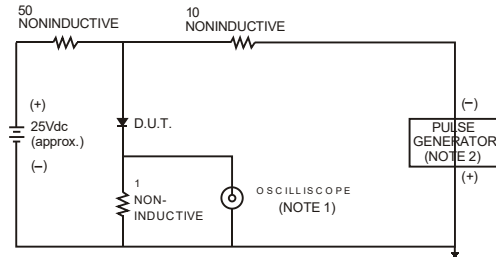
NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A

2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

RATING AND CHARACTERISTIC CURVES (ES2A THRU ES2J)

FIG.1- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm, 22pF.
2. Rise Time= 10ns max., Source Impedance= 50 ohms.

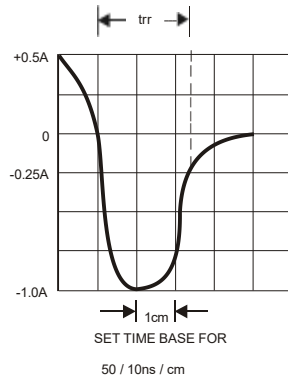


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

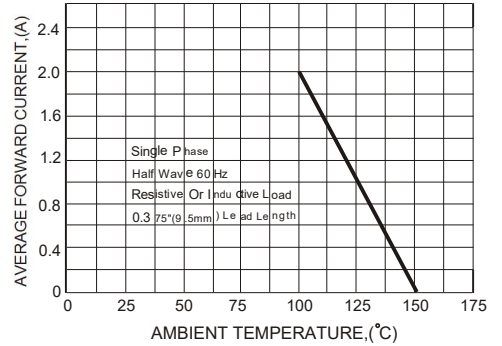


FIG.3-TYPICAL FORWARD CHARACTERISTICS

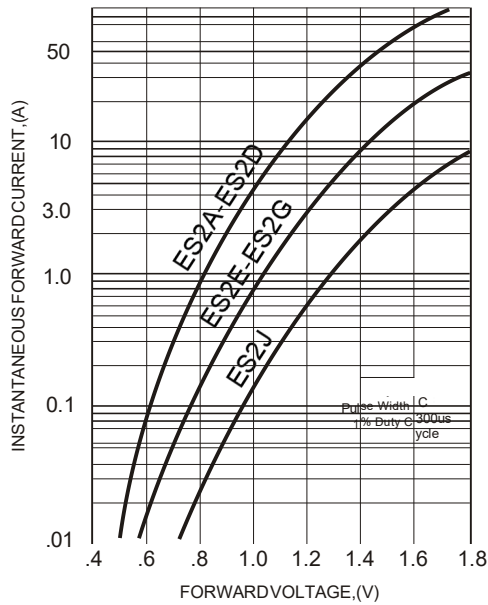


FIG.4-TYPICAL REVERSE CHARACTERISTICS

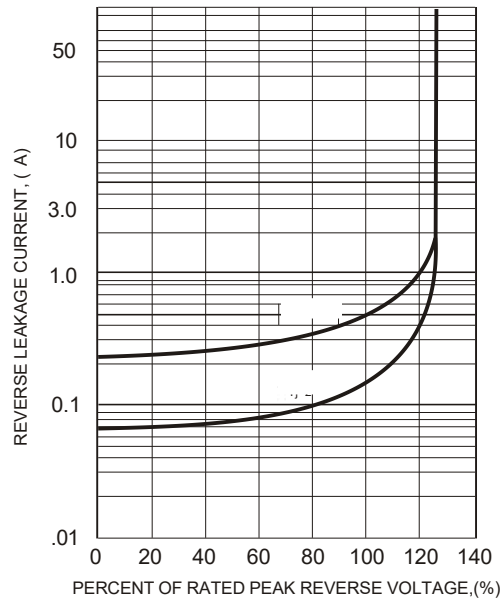


FIG.5-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

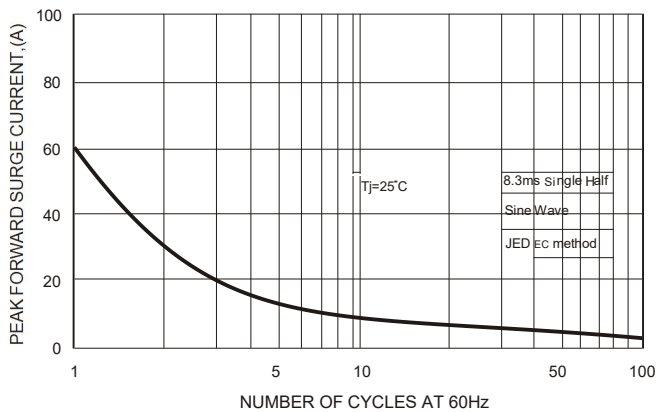
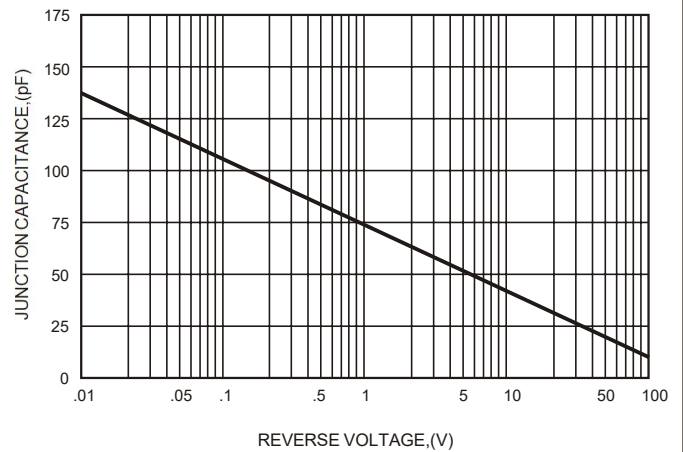


FIG.6-TYPICAL JUNCTION CAPACITANCE



单击下面可查看定价，库存，交付和生命周期等信息

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